

# CMS16N06D-HF

**N-Channel  
RoHS Device  
Halogen Free**



## Features

- Low reverse transfer capacitance.
- High switching speed.
- Improved dv/dt capability.
- 100% EAS guaranteed.
- Green device available.

## Mechanical data

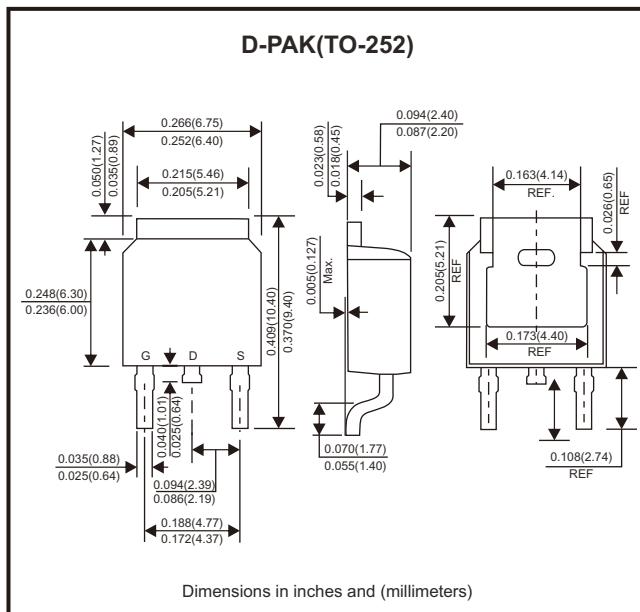
- Case: D-PAK/TO-252 standard package, molded plastic.

## Description

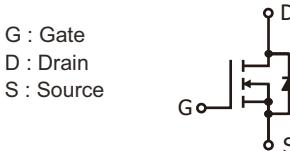
The CMS16N06D is the highest performance N-ch MOSFETs with super high dense cell density for extremely low RDS(ON) and gate charge for most of the synchronous buck converter applications. The CMS16N06D meet the ROHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

## Maximum Ratings (at TA=25°C unless otherwise noted)

| Parameter  | Conditions             | Symbol                            | Value       | Unit |
|--|------------------------|-----------------------------------|-------------|------|
| Drain-source voltage                             |                        | V <sub>DS</sub>                   | 60          | V    |
| Gate-source voltage                              |                        | V <sub>GS</sub>                   | ±20         | V    |
| Continuous drain current (Note 1)                | T <sub>c</sub> = 25°C  | I <sub>D</sub>                    | 16          | A    |
|  | T <sub>c</sub> = 100°C | I <sub>D</sub>                    | 10          |      |
| Pulsed drain current (Note 1, 2)                 | T <sub>c</sub> = 25°C  | I <sub>DM</sub>                   | 64          | A    |
| Continuous drain current                         | T <sub>A</sub> = 25°C  | I <sub>D</sub>                    | 4.4         | A    |
|  | T <sub>A</sub> = 70°C  | I <sub>D</sub>                    | 3.5         |      |
| Total power dissipation (Note 4)                 | T <sub>c</sub> = 25°C  | P <sub>D</sub>                    | 27          | W    |
|  | T <sub>A</sub> = 25°C  | P <sub>D</sub>                    | 2           |      |
| Single pulse avalanche energy, L=0.1mH (Note 3)  |                        | E <sub>AS</sub>                   | 11          | mJ   |
| Single pulse avalanche current, L=0.1mH (Note 3) |                        | I <sub>AS</sub>                   | 15          | A    |
| Operating junction and storage temperature range |                        | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |



## Circuit Diagram



## Thermal Data

| Parameter                                    | Conditions   | Symbol           | Max. Value | Unit |
|--|--------------|------------------|------------|------|
| Thermal resistance junction-ambient (Note 1) | Steady state | R <sub>θJA</sub> | 62.5       | °C/W |
| Thermal resistance junction-case (Note 1)    | Steady state | R <sub>θJC</sub> | 4.6        | °C/W |

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## Electrical Characteristics (at $T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter                                   | Symbol                            | Min | Typ  | Max       | Unit             | Conditions   |
|---|-----------------------------------|-----|------|-----------|------------------|--|
| Drain-source breakdown voltage              | $\text{BV}_{\text{DSS}}$          | 60  |      |           | V                | $\text{V}_{\text{GS}} = 0, \text{I}_D = 250\mu\text{A}$  |
| Gate threshold voltage                      | $\text{V}_{\text{GS}(\text{th})}$ | 1.0 | 1.8  | 2.5       | V                | $\text{V}_{\text{DS}} = \text{V}_{\text{GS}}, \text{I}_D = 250\mu\text{A}$   |
| Gate-source leakage current                 | $\text{I}_{\text{GSS}}$           |     |      | $\pm 100$ | nA               | $\text{V}_{\text{GS}} = \pm 20\text{V}$  |
| Drain-source leakage current                | $\text{I}_{\text{DSS}}$           |     |      | 1         | $\mu\text{A}$    | $\text{V}_{\text{DS}} = 60\text{V}, \text{V}_{\text{GS}} = 0$  |
| Static drain-source on-resistance (Note 2)  | $\text{R}_{\text{DS}(\text{on})}$ |     | 37   | 50        | $\text{m}\Omega$ | $\text{V}_{\text{GS}} = 10\text{V}, \text{I}_D = 8\text{A}$  |
|   |                                   |     | 42   | 60        |                  | $\text{V}_{\text{GS}} = 4.5\text{V}, \text{I}_D = 4\text{A}$   |
| Total gate charge (Note 2)                  | $\text{Q}_g$                      |     | 14   |           | nC               | $\text{I}_D = 4\text{A}, \text{V}_{\text{DS}} = 30\text{V}, \text{V}_{\text{GS}} = 10\text{V}$                         |
| Gate-source charge                          | $\text{Q}_{\text{gs}}$            |     | 2.9  |           |                  |  |
| Gate-drain ("Miller") charge                | $\text{Q}_{\text{gd}}$            |     | 2.3  |           |                  |  |
| Turn-on delay time (Note 2)                 | $\text{t}_{\text{d}(\text{on})}$  |     | 3.9  |           | ns               | $\text{V}_{\text{DS}} = 30\text{V}, \text{I}_D = 1\text{A}, \text{V}_{\text{GS}} = 10\text{V}, \text{R}_G = 3.3\Omega$ |
| Rise time                                   | $\text{t}_r$                      |     | 13   |           |                  |  |
| Turn-off delay time                         | $\text{t}_{\text{d}(\text{off})}$ |     | 23   |           |                  |  |
| Fall time                                   | $\text{t}_f$                      |     | 6.7  |           |                  |  |
| Input capacitance                           | $\text{C}_{\text{iss}}$           |     | 815  |           | pF               | $\text{V}_{\text{GS}} = 0\text{V}, \text{V}_{\text{DS}} = 15\text{V}, f = 1\text{MHz}$                                 |
| Output capacitance                          | $\text{C}_{\text{oss}}$           |     | 379  |           |                  |  |
| Reverse transfer capacitance                | $\text{C}_{\text{rss}}$           |     | 110  |           |                  |  |
| <b>Guaranteed avalanche characteristics</b> |                                   |     |      |           |                  |  |
| Single pulse avalanche energy (Note 5)      | EAS                               | 3.2 |      |           | mJ               | $\text{V}_{\text{DD}} = 25\text{V}, L = 0.1\text{mH}, \text{IAS} = 8\text{A}$  |
| <b>Source-drain diode</b>                   |                                   |     |      |           |                  |  |
| Diode forward voltage (Note 2)              | $\text{V}_{\text{SD}}$            |     | 0.73 | 1.0       | V                | $\text{I}_S = 1\text{A}, \text{V}_{\text{GS}} = 0\text{V}, \text{T}_J = 25^\circ\text{C}$                              |
| Continuous source current (Note 1, 6)       | $\text{I}_S$                      |     |      | 16        | A                |  |

Notes: 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.

2. The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

3. The EAS data shows Max. rating. The test condition is  $\text{V}_{\text{DD}}=25\text{V}, \text{V}_{\text{GS}}=10\text{V}, L=0.1\text{mH}, \text{IAS}=15\text{A}$ .

4. The power dissipation is limited by  $150^\circ\text{C}$  junction temperature.

5. The min. value is 100% EAS tested guarantee.

6. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.

## Rating and Characteristic Curves (CMS16N06D-HF)

### Typical Characteristics

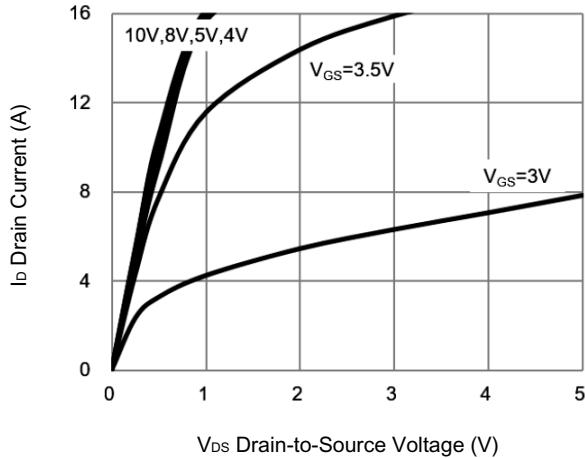


Fig.1 Typical Output Characteristics

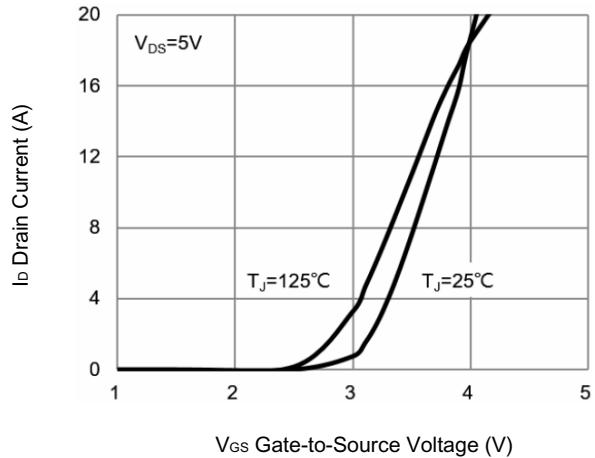


Fig.2 Transfer Characteristics

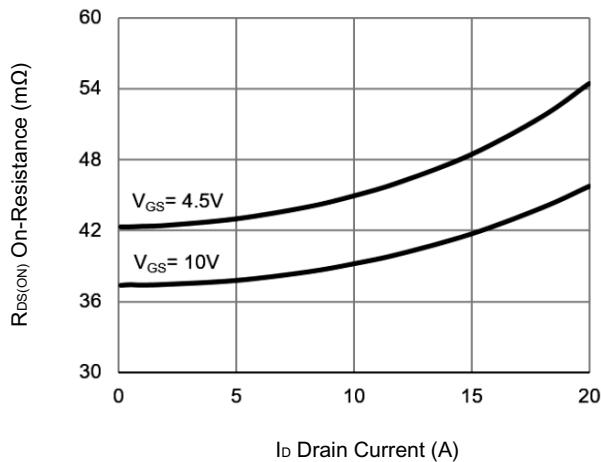


Fig.3 On-Resistance vs. Drain Current

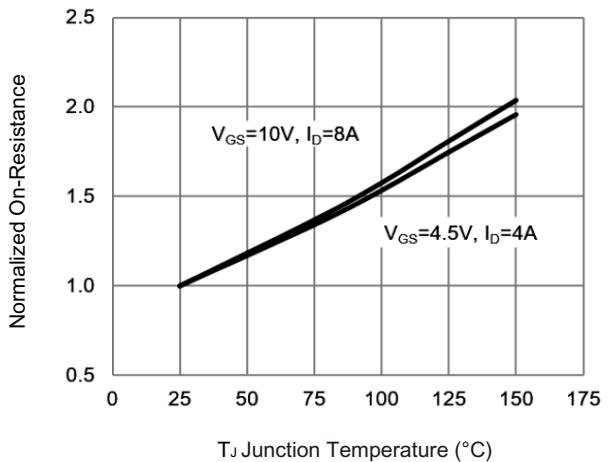


Fig.4 Normalized  $R_{DS(on)}$  vs.  $T_J$

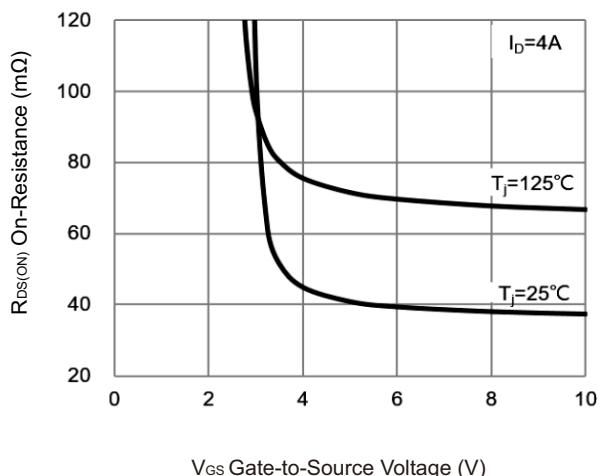


Fig.5 On-Resistance vs. G-S Voltage

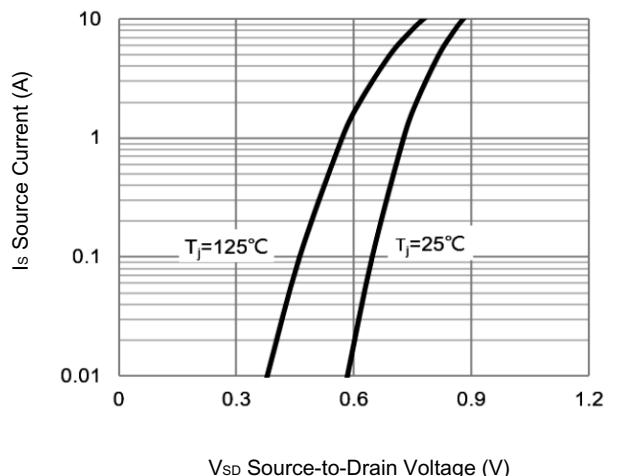


Fig.6 Forward Characteristics of Reverse

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## Rating and Characteristic Curves (CMS16N06D-HF)

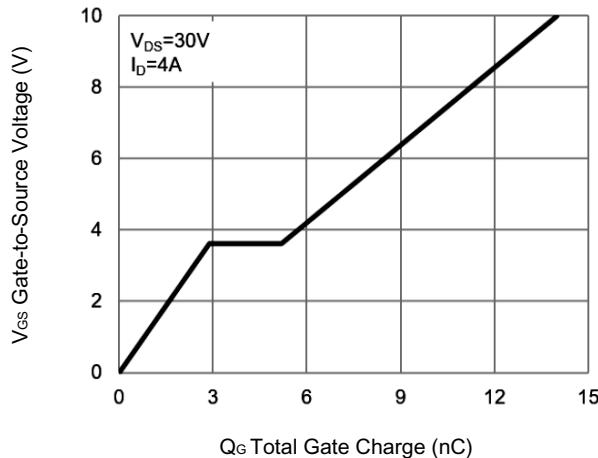


Fig.7 Gate Charge Characteristics

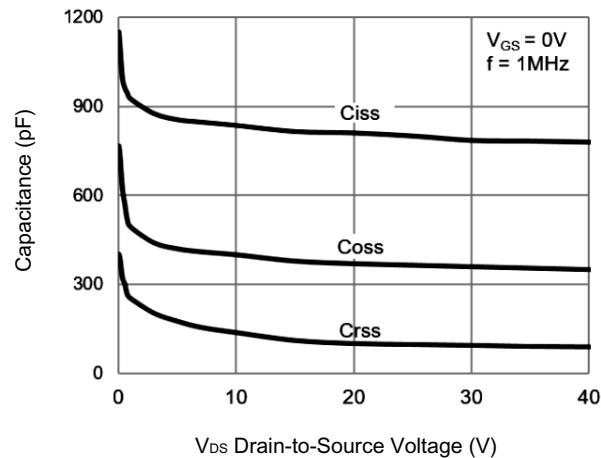


Fig.8 Capacitance Characteristics

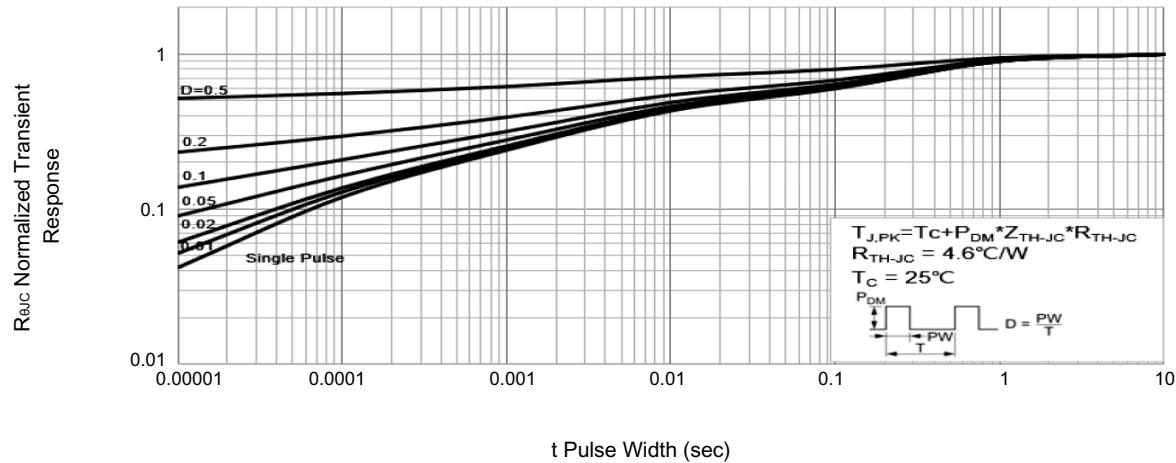


Fig.9 Normalized Maximum Transient Thermal Impedance

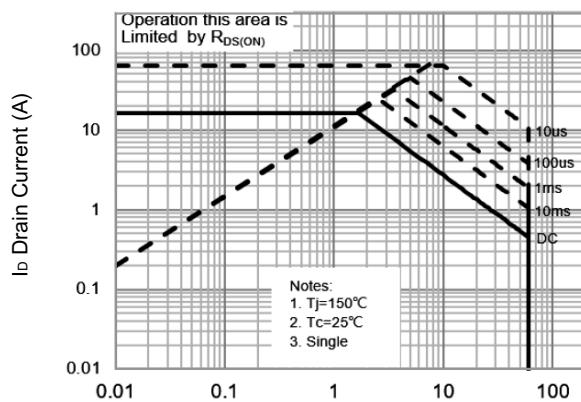


Fig.10 Safe Operating Area

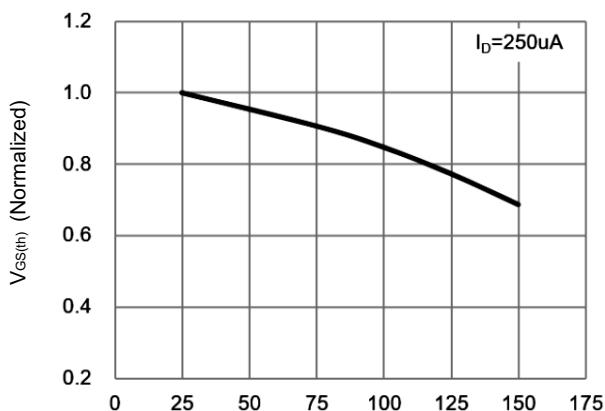
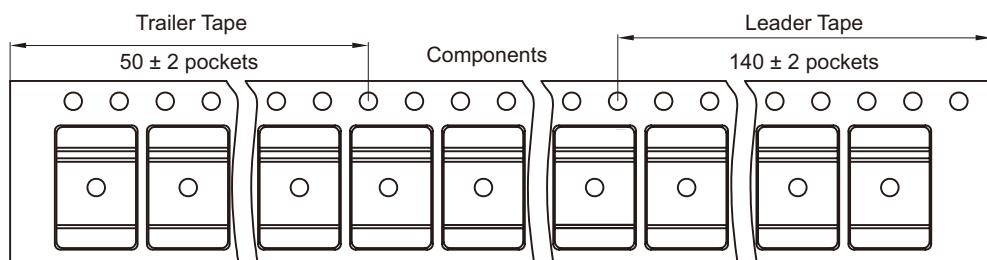
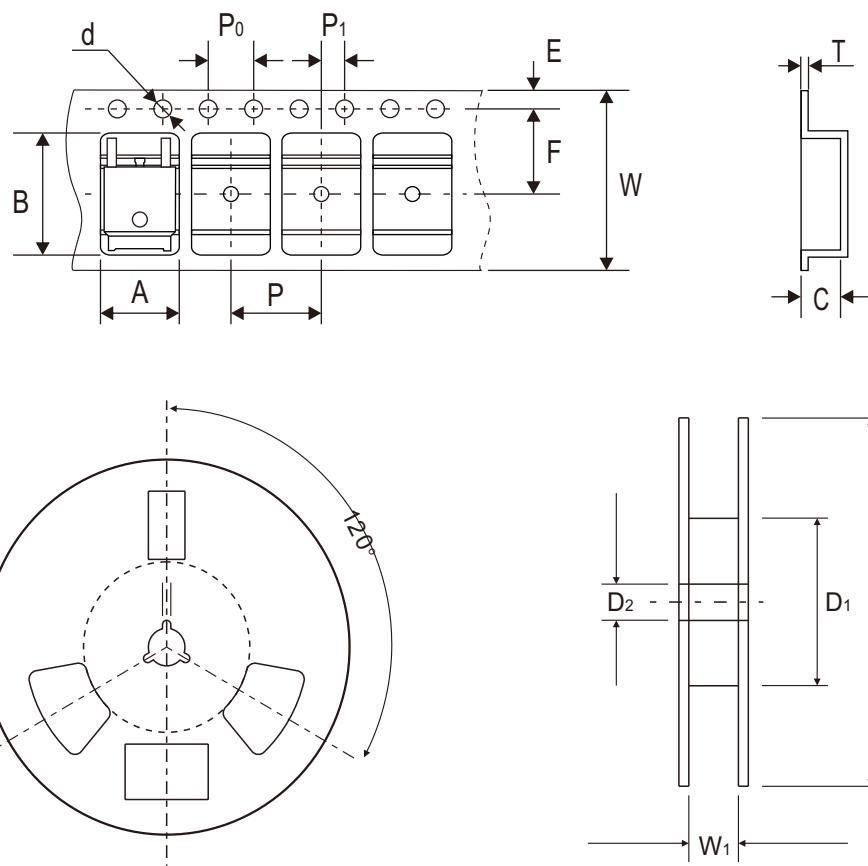


Fig.11 Normalized  $V_{GS(th)}$  vs. Temperature

## Reel Taping Specification



| TO-252<br>(D-PAK) | SYMBOL | A             | B             | C             | d             | D              | D1            | D2            |
|-------------------|--------|---------------|---------------|---------------|---------------|----------------|---------------|---------------|
|                   | (mm)   | 6.90 ± 0.10   | 10.50 ± 0.10  | 2.78 ± 0.10   | 1.50 ± 0.10   | 330 ± 1.00     | 100.00 ± 0.50 | 13.20 ± 0.20  |
|                   | (inch) | 0.272 ± 0.004 | 0.413 ± 0.004 | 0.109 ± 0.004 | 0.059 ± 0.004 | 12.992 ± 0.039 | 3.937 ± 0.020 | 0.520 ± 0.008 |

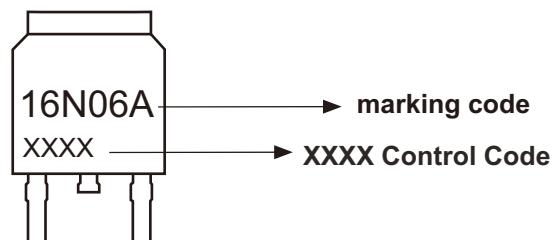
| TO-252<br>(D-PAK) | SYMBOL | E             | F             | P             | P <sub>0</sub> | P <sub>1</sub> | T             | W             | W <sub>1</sub> |
|-------------------|--------|---------------|---------------|---------------|----------------|----------------|---------------|---------------|----------------|
|                   | (mm)   | 1.75 ± 0.10   | 7.50 ± 0.10   | 8.00 ± 0.10   | 4.00 ± 0.10    | 2.00 ± 0.10    | 0.25 ± 0.02   | 16.00 ± 0.10  | 16.40 ± 0.02   |
|                   | (inch) | 0.069 ± 0.004 | 0.295 ± 0.004 | 0.315 ± 0.004 | 0.157 ± 0.004  | 0.079 ± 0.004  | 0.010 ± 0.001 | 0.630 ± 0.004 | 0.646 ± 0.01   |

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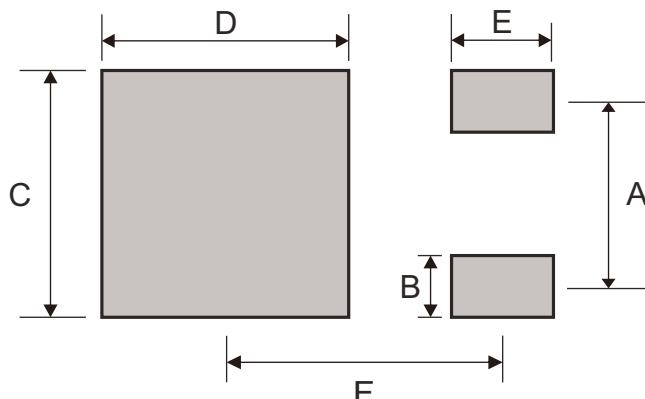
## Marking Code

| Part Number  | Marking Code |
|--------------|--------------|
| CMS16N06D-HF | 16N06A       |



## Suggested P.C.B. PAD Layout

| SIZE | TO-252 / DPAK |        |
|------|---------------|--------|
|      | (mm)          | (inch) |
| A    | 4.60          | 0.181  |
| B    | 1.40          | 0.055  |
| C    | 6.00          | 0.236  |
| D    | 6.50          | 0.256  |
| E    | 3.00          | 0.118  |
| F    | 6.25          | 0.246  |



Note: 1. The pad layout is for reference purposes only.

## Standard Packaging

| Case Type    | REEL PACK       |                     |
|--------------|-----------------|---------------------|
|              | REEL<br>( pcs ) | REEL SIZE<br>(inch) |
| TO-252/D-PAK | 2,500           | 13                  |